### FAIRCHILD

SEMICONDUCTOR®

# FDS6692A N-Channel PowerTrench<sup>®</sup> MOSFET 30V, 9A, 11.5mΩ

### Features

- $R_{DS(ON)} = 11.5m\Omega$ ,  $V_{GS} = 10V$ ,  $I_D = 9A$
- R<sub>DS(ON)</sub> = 14.5mΩ, V<sub>GS</sub> = 4.5V, I<sub>D</sub> = 8.2A
- High performance trench technology for extremely low R<sub>DS(ON)</sub>
- Low gate charge
- High power and current handling capability
- RoHS Compliant

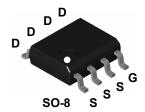
### Applications

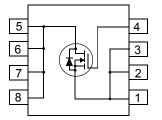
DC/DC converters

### **General Description**

This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low  $R_{DS(ON)}$  and fast switching speed.







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Symbol	Parameter	Ratings	Units
V <sub>DSS</sub>	Drain to Source Voltage	30	V
V <sub>GS</sub>	Gate to Source Voltage	±20	V
	Drain Current		
	Continuous ( $T_A = 25^{\circ}C$ , $V_{GS} = 10V$ , $R_{\theta JA} = 85^{\circ}C/W$ )	9	Α
D	Continuous ( $T_A = 25^{\circ}C$ , $V_{GS} = 4.5V$ , $R_{\theta JA} = 85^{\circ}C/W$ )	8.2	Α
	Pulsed	48	Α
E <sub>AS</sub>	Single Pulse Avalanche Energy (Note 1)	79	mJ
P <sub>D</sub>	Power dissipation	1.47	W
TJ, T <sub>STG</sub>	Operating and Storage Temperature	-55 to 150	°C

# H<sub>0JA</sub> I hermal Hesistance, Junction to Ambient at 10 seconds (Note 3) 50 R<sub>0JA</sub> Thermal Resistance, Junction to Ambient at 1000 seconds (Note 3) 85

### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS6692A	FDS6692A	SO-8	330mm	12mm	2500 units

## **Electrical Characteristics** $T_J = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Charac	cteristics					

B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{GS} = 0 V$	30	-	-	V
$\Delta B_{VDSS} \Delta T_J$	Breakdown Voltage Temp. Coefficient	$I_D = 250\mu A$ , Referenced to $25^{\circ}C$	-	21	-	mV/ºC
1	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 24V	-	-	1	μA
DSS	Zero Gate voltage Drain Current	$V_{GS} = 0V$ $T_J = 15$	50°C -	-	250	μΑ
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20V$	-	-	±100	nA

### **On Characteristics**

V <sub>GS(TH)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	1.2	-	2.5	V
$\frac{\Delta V_{GS(TH)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \mu A$ , Referenced to $25^{\circ}C$	-	-5	-	mV/ºC
	Drain to Source On Resistance	I <sub>D</sub> = 9A, V <sub>GS</sub> = 10V	-	8.2	11.5	
R <sub>DS(ON)</sub>		I <sub>D</sub> = 8.2A, V <sub>GS</sub> = 4.5V	-	11	14.5	mΩ
20(011)		$I_D = 9A, V_{GS} = 10V,$ $T_J = 150^{\circ}C$	-	13	19	- 1115.2

### **Dynamic Characteristics**

CISS	Input Capacitance			-	1210	1610	pF
C <sub>OSS</sub>	Output Capacitance	$V_{DS} = 15V, V_{GS}$ = 1 MHz	= 0V,	-	330	440	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance			-	138	210	pF
R <sub>G</sub>	Gate Resistance	f = 1MHz		-	2.0	-	Ω
Q <sub>g(TOT)</sub>	Total Gate Charge at 10V	V <sub>GS</sub> = 0V to 10V		-	22	29	nC
Q <sub>g(5)</sub>	Total Gate Charge at 5V	$V_{GS} = 0V$ to 5V	V <sub>DD</sub> = 15V	-	12	16	nC
Q <sub>g(TH)</sub>	Threshold Gate Charge	$V_{GS} = 0V$ to 1V	I <sub>D</sub> = 9A	-	0.93	1.2	nC
Q <sub>gs</sub>	Gate to Source Gate Charge		l <sub>g</sub> = 1.0mA	-	3	-	nC
Q <sub>gs2</sub>	Gate Charge Threshold to Plateau			-	2.1	-	nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			-	4.8	-	nC

°C/W

Switchir	ng Characteristics (V <sub>GS</sub> = 10V)					
t <sub>ON</sub>	Turn-On Time		-	-	60	ns
t <sub>d(ON)</sub>	Turn-On Delay Time		-	8	-	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 15V, I <sub>D</sub> = 9A	-	32	-	ns
t <sub>d(OFF)</sub>	Turn-Off Delay Time	$V_{GS} = 10V, R_{GS} = 6.2\Omega$	-	33	-	ns
t <sub>f</sub>	Fall Time		-	13	-	ns
t <sub>OFF</sub>	Turn-Off Time		-	-	69	ns

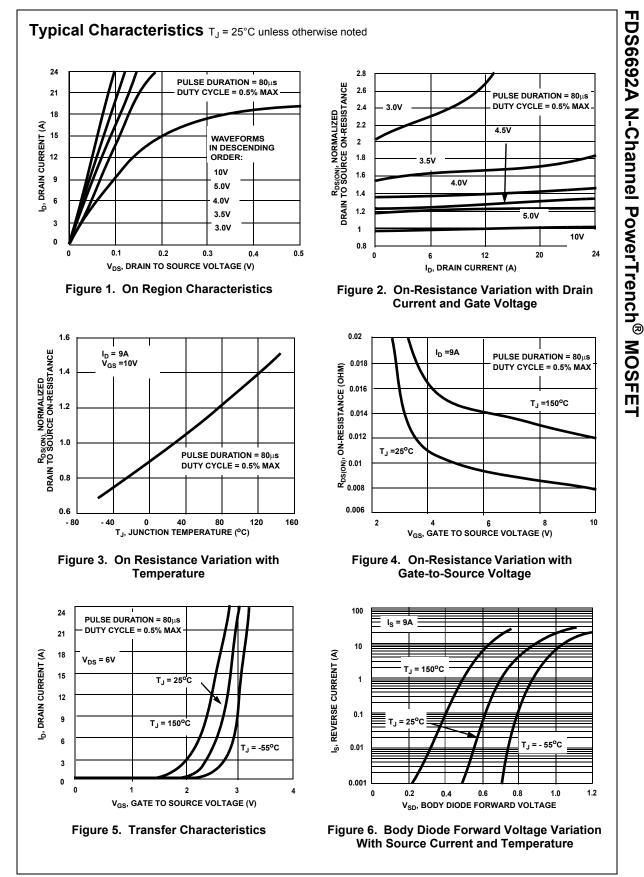
### **Drain-Source Diode Characteristics**

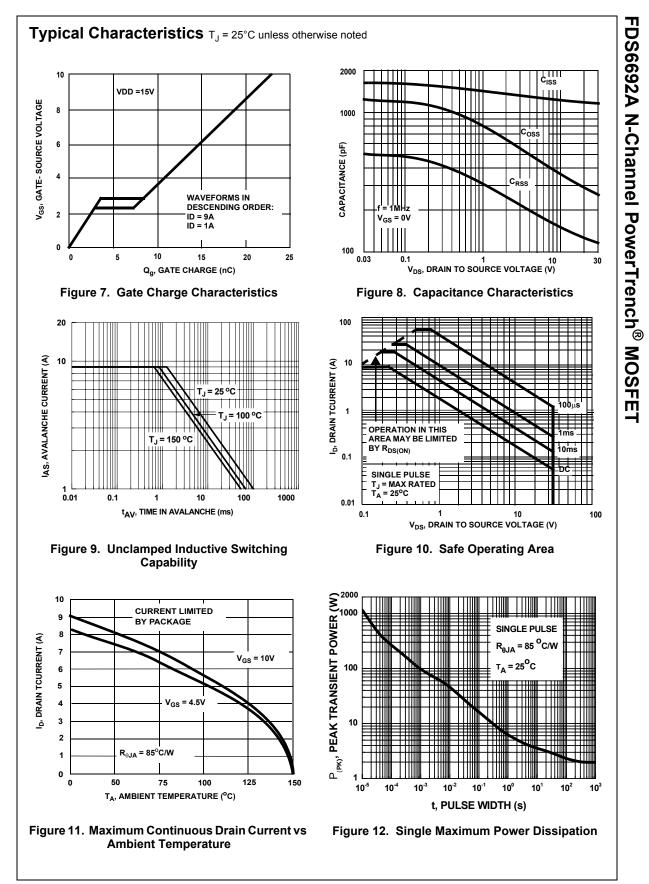
V.	Source to Drain Diode Voltage	I <sub>SD</sub> = 9A	-	-	1.25	V
V <sub>SD</sub> Source to Drain Diode Voltage	I <sub>SD</sub> = 2.1A	-	-	1.0	V	
t <sub>rr</sub>	Reverse Recovery Time	$I_{SD} = 9A$ , $dI_{SD}/dt = 100A/\mu s$	-	-	27	ns
Q <sub>RR</sub>	Reverse Recovered Charge	$I_{SD} = 9A, dI_{SD}/dt = 100A/\mu s$	-	-	17	nC

Notes:

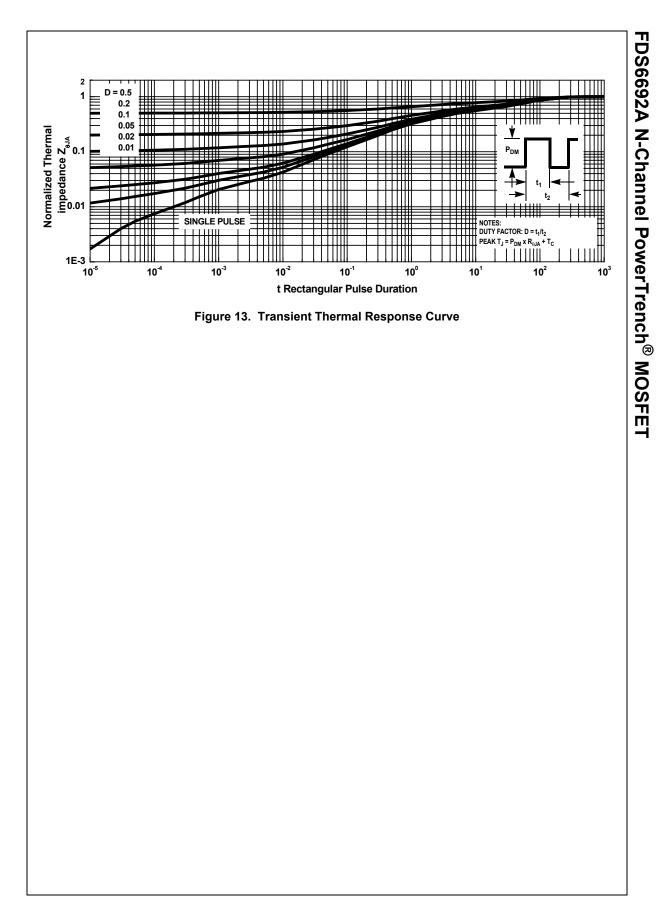
1: Starting T<sub>J</sub> = 25°C, L = 0.3mH, I<sub>AS</sub> = 23A, V<sub>DD</sub> = 27V, V<sub>GS</sub> = 10V.
2: R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>0JC</sub> is guaranteed by design while R<sub>0JA</sub> is determined by the user's board design.
3: R<sub>0JA</sub> is measured with 1.0 in<sup>2</sup> copper on FR-4 board

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